

Advance Information

128K x 8 Bit Fast Static Random Access Memory

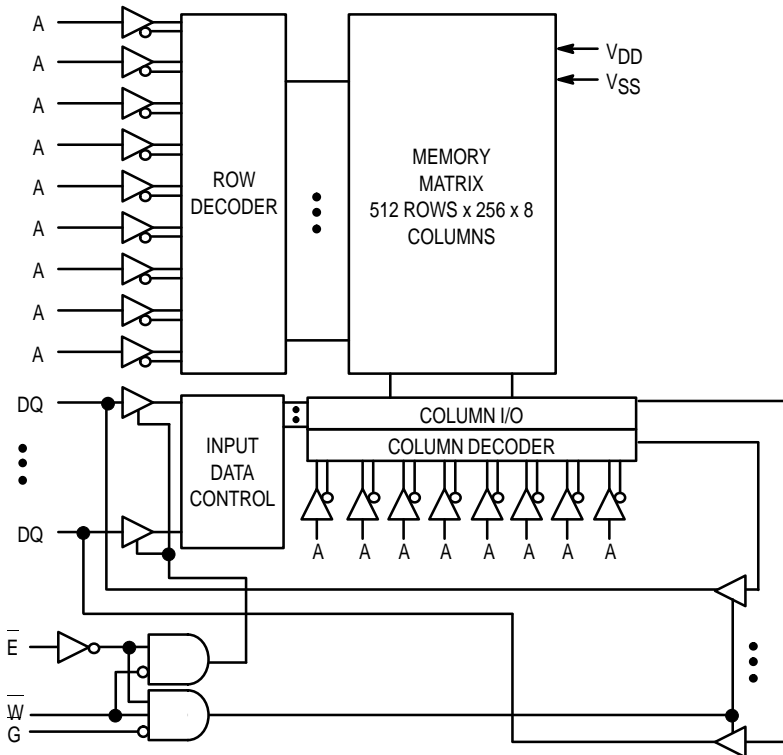
The MCM6926A is a 1,048,576 bit static random access memory organized as 131,072 words of 8 bits. Static design eliminates the need for external clocks or timing strobes.

Output enable (G) is a special control feature that provides increased system flexibility and eliminates bus contention problems.

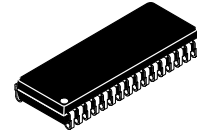
This device meets JEDEC standards for functionality and revolutionary pinout, and is available in a 400 mil plastic small-outline J-leaded package.

- Single 3.3 V Power Supply
- Fully Static — No Clock or Timing Strokes Necessary
- All Inputs and Outputs Are TTL Compatible
- Three State Outputs
- Fast Access Times: 8, 10, 12, 15 ns
- Center Power and I/O Pins for Reduced Noise
- Fully 3.3 V BiCMOS

BLOCK DIAGRAM



MCM6926A



WJ PACKAGE
400 MIL SOJ
CASE 857A-02

PIN ASSIGNMENT

A	1	32	A
A	2	31	A
A	3	30	A
A	4	29	A
\bar{E}	5	28	\bar{G}
DQ	6	27	DQ
DQ	7	26	DQ
V _{DD}	8	25	V _{SS}
V _{SS}	9	24	V _{DD}
DQ	10	23	DQ
DQ	11	22	DQ
\bar{W}	12	21	A
A	13	20	A
A	14	19	A
A	15	18	A
A	16	17	A

PIN NAMES

A	Address Input
\bar{E}	Chip Enable
\bar{W}	Write Enable
G	Output Enable
DQ	Data Input/Output
V _{DD}	+ 3.3 V Power Supply
V _{SS}	Ground

This document contains information on a new product. Motorola reserves the right to change or discontinue this product without notice.

REV 1
2/25/97

TRUTH TABLE (X = Don't Care)

E	G	W	Mode	V _{DD} Current	Output	Cycle
H	X	X	Not Selected	I _{SB1} , I _{SB2}	High-Z	—
L	H	H	Output Disabled	I _{DDA}	High-Z	—
L	L	H	Read	I _{DDA}	D _{out}	Read Cycle
L	X	L	Write	I _{DDA}	High-Z	Write Cycle

ABSOLUTE MAXIMUM RATINGS (See Note)

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{DD}	- 0.5 to + 4.6	V
Voltage Relative to V _{SS} for Any Pin Except V _{DD}	V _{in} , V _{out}	- 0.5 to V _{DD} + 0.5	V
Output Current	I _{out}	± 30	mA
Power Dissipation	P _D	0.6	W
Temperature Under Bias	T _{bias}	- 10 to + 85	°C
Operating Temperature	T _A	0 to + 70	°C
Storage Temperature — Plastic	T _{stg}	- 55 to + 125	°C

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPERATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to these high-impedance circuits.

This BiCMOS memory circuit has been designed to meet the dc and ac specifications shown in the tables, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow of at least 500 linear feet per minute is maintained.

DC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{DD} = 3.3 V + 10%, - 5%, T_A = 0 to 70°C, Unless Otherwise Noted)

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage (Operating Voltage Range)	V _{DD}	3.135	3.3	3.6	V
Input High Voltage	V _{IH}	2.2	—	V _{DD} + 0.3**	V
Input Low Voltage	V _{IL}	- 0.5*	—	0.8	V

* V_{IL} (min) = - 0.5 V dc; V_{IL} (min) = - 2.0 V ac (pulse width ≤ 2.0 ns) for I ≤ 20.0 mA.

** V_{IH} (max) = V_{DD} + 0.3 V dc; V_{IH} (max) = V_{DD} + 2 V ac (pulse width ≤ 2.0 ns) for I ≤ 20.0 mA.

DC CHARACTERISTICS

Parameter	Symbol	Min	Max	Unit
Input Leakage Current (All Inputs, V _{in} = 0 to V _{DD})	I _{lkg(I)}	—	± 1.0	μA
Output Leakage Current (E = V _{IH} , V _{out} = 0 to V _{DD})	I _{lkg(O)}	—	± 1.0	μA
Output Low Voltage (I _{OL} = + 8.0 mA)	V _{OL}	—	0.4	V
Output High Voltage (I _{OH} = - 4.0 mA)	V _{OH}	2.4	—	V

POWER SUPPLY CURRENTS (See Note 1)

Parameter	Symbol	6926A-8		6926A-10		6926A-12		6926A-15		Unit	Notes
		Typ	Max	Typ	Max	Typ	Max	Typ	Max		
AC Active Supply Current ($I_{out} = 0 \text{ mA}$) ($V_{DD} = \text{max}$, $f = f_{max}$)	I_{DDA}	—	150	—	130	—	120	—	110	mA	2, 3, 4
Active Quiescent Current ($E = V_{IL}$, $V_{DD} = \text{max}$, $f = 0 \text{ MHz}$)	I_{DD2}	—	80	—	80	—	80	—	80	mA	
AC Standby Current ($E = V_{IH}$, $V_{DD} = \text{max}$, $f = f_{max}$)	I_{SB1}	—	50	—	45	—	40	—	35	mA	2, 3, 4
CMOS Standby Current ($V_{DD} = \text{max}$, $f = 0 \text{ MHz}$, $E \geq V_{DD} - 0.2 \text{ V}$, $V_{in} \leq V_{SS} + 0.2 \text{ V}$, or $\geq V_{DD} - 0.2 \text{ V}$)	I_{SB2}	—	20	—	20	—	20	—	20	mA	

NOTES:

1. Typical current = 25°C @ 3.3 V.
2. Reference AC Operating Conditions and Characteristics for input and timing (V_{IH}/V_{IL} , t_r/t_f , pulse level 0 to 3.0 V, $V_{IH} = 3.0 \text{ V}$).
3. All address transition simultaneously low (LSB) and then high (MSB).
4. Data states are all zero.

CAPACITANCE ($f = 1.0 \text{ MHz}$, $dV = 3.0 \text{ V}$, $T_A = 25^\circ\text{C}$, Periodically Sampled Rather Than 100% Tested)

Parameter	Symbol	Typ	Max	Unit
Address Input Capacitance	C_{in}	—	6	pF
Control Pin Input Capacitance	C_{in}	—	6	pF
Input/Output Capacitance	$C_{I/O}$	—	8	pF

AC OPERATING CONDITIONS AND CHARACTERISTICS

($V_{DD} = 3.3\text{ V} + 10\%, -5\%$, $T_A = 0\text{ to }+70^\circ\text{C}$, Unless Otherwise Noted)

Input Timing Measurement Reference Level 1.5 V
 Input Pulse Levels 0 to 3.0 V
 Input Rise/Fall Time 2 ns

Output Timing Measurement Reference Level 1.5 V
 Output Load See Figure 1

READ CYCLE TIMING (See Notes 1 and 2)

Parameter	Symbol	6926A-8		6926A-10		6926A-12		6926A-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Read Cycle Time	t_{AVAV}	8	—	10	—	12	—	15	—	ns	3
Address Access Time	t_{AVQV}	—	8	—	10	—	12	—	15	ns	
Enable Access Time	t_{ELQV}	—	8	—	10	—	12	—	15	ns	
Output Enable Access Time	t_{GLQV}	—	4	—	5	—	6	—	7	ns	
Output Hold from Address Change	t_{AXQX}	3	—	3	—	3	—	3	—	ns	
Enable Low to Output Active	t_{ELQX}	3	—	3	—	3	—	3	—	ns	4, 5, 6
Output Enable Low to Output Active	t_{GLQX}	0	—	0	—	0	—	0	—	ns	4, 5, 6
Enable High to Output High-Z	t_{EHQZ}	—	4	—	5	—	6	—	7	ns	4, 5, 6
Output Enable High to Output High-Z	t_{GHQZ}	—	4	—	5	—	6	—	7	ns	4, 5, 6

NOTES:

1. W is high for read cycle.
2. For common I/O applications, minimization or elimination of bus contention conditions is necessary during read and write cycles.
3. All read cycle timings are referenced from the last valid address to the first transitioning address.
4. At any given voltage and temperature, $t_{EHQZ}\text{ max} < t_{ELQX}\text{ min}$, and $t_{GHQZ}\text{ max} < t_{GLQX}\text{ min}$, both for a given device and from device to device.
5. Transition is measured 200 mV from steady-state voltage.
6. This parameter is sampled and not 100% tested.
7. Device is continuously selected ($E = V_{IL}$, $\bar{G} = V_{IL}$).
8. Addresses valid prior to or coincident with E going low.

TIMING LIMITS

The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time. On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

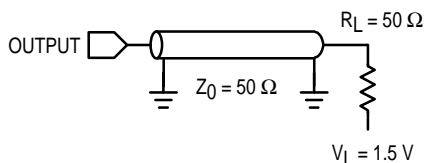
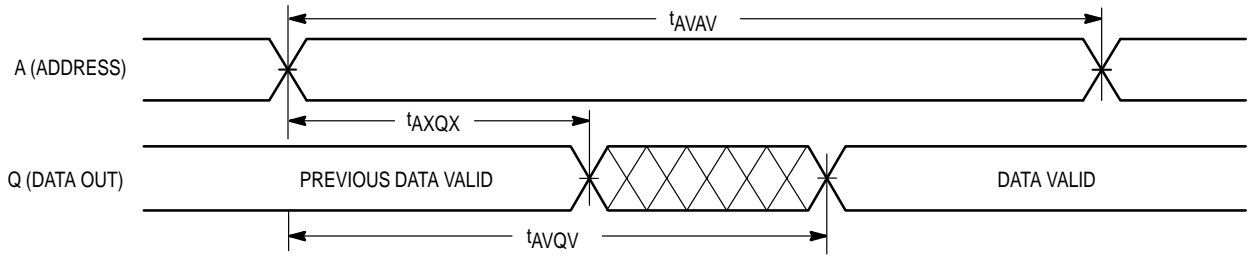
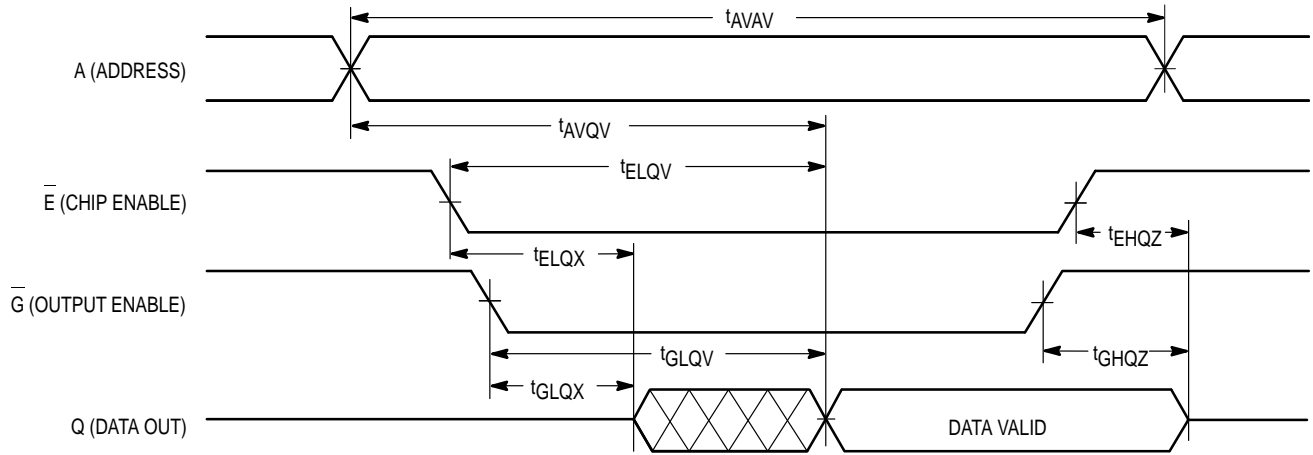


Figure 1. AC Test Load

READ CYCLE 1 (See Note 7)



READ CYCLE 2 (See Note 8)



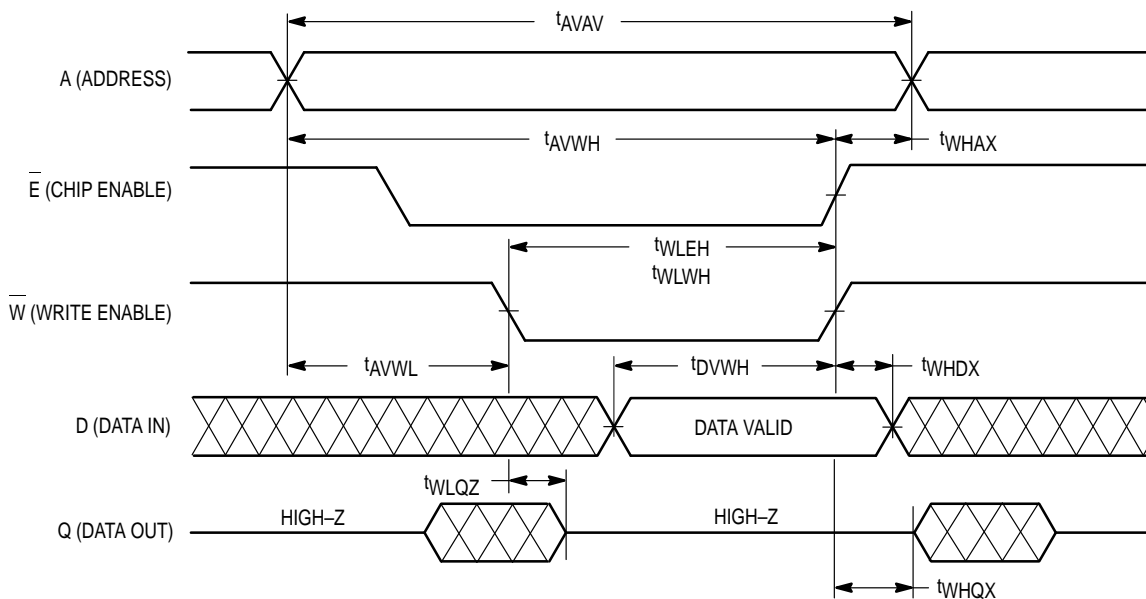
WRITE CYCLE 1 (\bar{W} Controlled, See Notes 1 and 2)

Parameter	Symbol	6926A-8		6926A-10		6926A-12		6926A-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	8	—	10	—	12	—	15	—	ns	3
Address Setup Time	t_{AVWL}	0	—	0	—	0	—	0	—	ns	
Address Valid to End of Write	t_{AVWH}	8	—	9	—	10	—	12	—	ns	
Address Valid to End of Write, G High	t_{AVWH}	7	—	8	—	9	—	10	—	ns	
Write Pulse Width	t_{WLWH} , t_{WLEH}	8	—	9	—	10	—	12	—	ns	
Write Pulse Width, G High	t_{WLWH} , t_{WLEH}	7	—	8	—	9	—	10	—	ns	
Data Valid to End of Write	t_{DVWH}	4	—	5	—	6	—	7	—	ns	
Data Hold Time	t_{WHDX}	0	—	0	—	0	—	0	—	ns	
Write Low to Data High-Z	t_{WLQZ}	—	4	—	5	—	6	—	7	ns	4,5,6
Write High to Output Active	t_{WHQX}	3	—	3	—	3	—	3	—	ns	4,5,6
Write Recovery Time	t_{WHAX}	0	—	0	—	0	—	0	—	ns	

NOTES:

1. A write occurs during the overlap of \bar{E} low and \bar{W} low.
2. For common I/O applications, minimization or elimination of bus contention conditions is necessary during read and write cycles.
3. All write cycle timings are referenced from the last valid address to the first transitioning address.
4. Transition is measured 200 mV from steady-state voltage.
5. This parameter is sampled and not 100% tested.
6. At any given voltage and temperature, $t_{WLQZ} \text{ max} < t_{WHQX} \text{ min}$ both for a given device and from device to device.

WRITE CYCLE 1

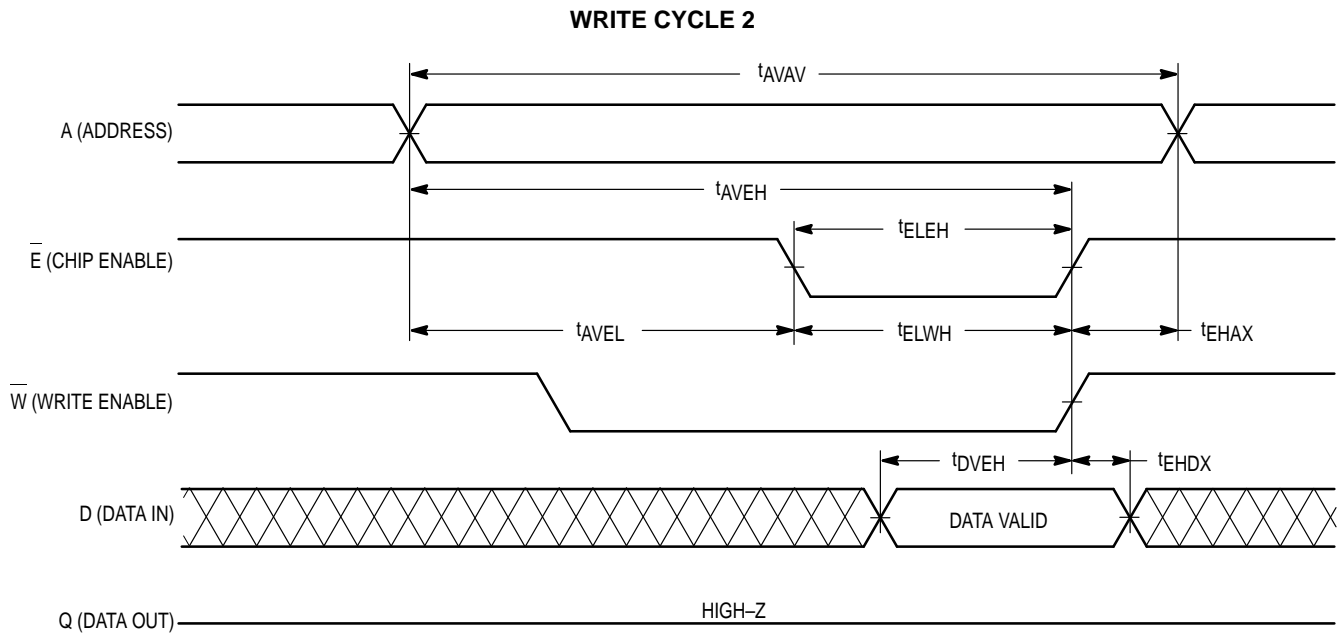


WRITE CYCLE 2 (\bar{E} Controlled, See Notes 1 and 2)

Parameter	Symbol	6926A-8		6926A-10		6926A-12		6926A-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	8	—	10	—	12	—	15	—	ns	3
Address Setup Time	t_{AVEL}	0	—	0	—	0	—	0	—	ns	
Address Valid to End of Write	t_{AVEH}	7	—	8	—	9	—	10	—	ns	
Enable to End of Write	t_{ELEH} , t_{ELWH}	7	—	8	—	9	—	10	—	ns	4,5
Data Valid to End of Write	t_{DVEH}	4	—	5	—	6	—	7	—	ns	
Data Hold Time	t_{EHDX}	0	—	0	—	0	—	0	—	ns	
Write Recovery Time	t_{EHAX}	0	—	0	—	0	—	0	—	ns	

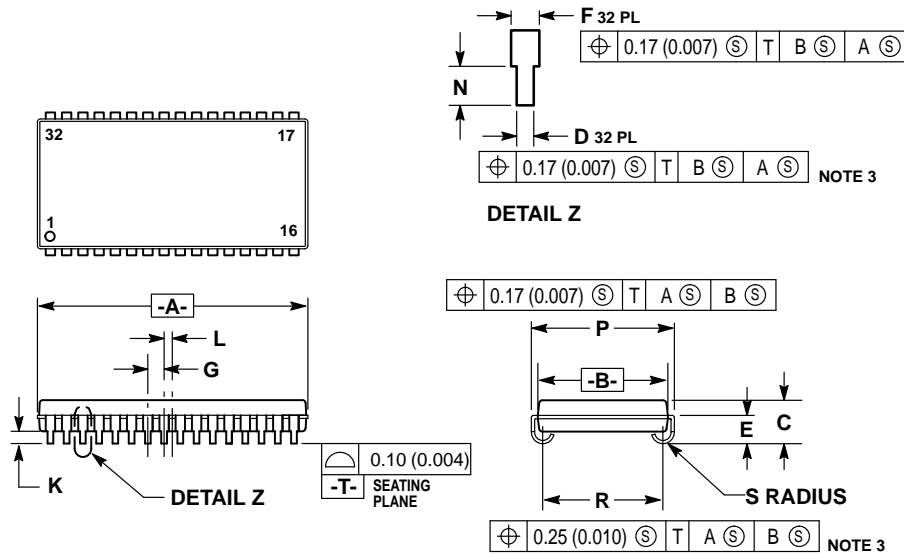
NOTES:

1. A write occurs during the overlap of \bar{E} low and \bar{W} low.
2. For common I/O applications, minimization or elimination of bus contention conditions is necessary during read and write cycles.
3. All write cycle timings are referenced from the last valid address to the first transitioning address.
4. If \bar{E} goes low coincident with or after \bar{W} goes low, the output will remain in a high impedance condition.
5. If \bar{E} goes high coincident with or before \bar{W} goes high, the output will remain in a high impedance condition.



PACKAGE DIMENSIONS

32-LEAD
400 MIL SOJ
CASE 857A-02

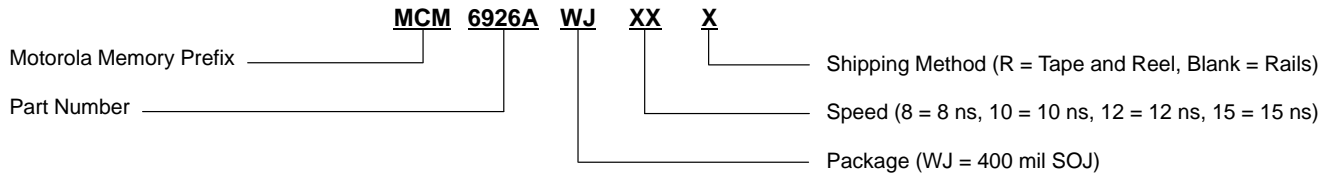


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. TO BE DETERMINED AT PLANE -T-
4. DIMENSION A & B DO NOT INCLUDE MOLD PROTRUSION. MOLD PROTRUSION SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
5. DIMENSION A & B INCLUDE MOLD MISMATCH AND ARE DETERMINED AT THE PARTING LINE.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.820	0.830	20.83	21.08
B	0.395	0.405	10.03	10.29
C	0.128	0.148	3.26	3.75
D	0.016	0.020	0.41	0.50
E	0.088	0.098	2.24	2.48
F	0.026	0.032	0.67	0.81
G	0.050 BSC		1.27 BSC	
K	0.035	0.045	0.89	1.14
L	0.025 BSC		0.64 BSC	
N	0.030	0.045	0.76	1.14
P	0.435	0.445	11.05	11.30
R	0.365	0.375	9.27	9.52
S	0.030	0.040	0.77	1.01

ORDERING INFORMATION (Order by Full Part Number)



Full Part Numbers — MCM6926AWJ8 MCM6926AWJ10 MCM6926AWJ12 MCM6926AWJ15
 MCM6926AWJ8R MCM6926AWJ10R MCM6926AWJ12R MCM6926AWJ15R

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